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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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# XBS013S16R-G



ETR1604-003

## Schottky Barrier Diode, 100mA, 30V Type

### **■**FEATURES

## **■**APPLICATIONS

Forward Voltage : V<sub>F</sub>=0.71V (TYP.) Forward Current :  $I_{F(AV)}$ =100mA Repetitive Peak Reverse Voltage : V<sub>RM</sub>=30V

Low Current Rectification

**Environmentally Friendly** : EU RoHS Compliant, Pb Free

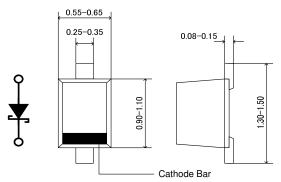
## ■ ABSOLUTE MAXIMUM RATINGS

## ■ PACKAGING INFORMATION

|                           |        |                   | 14-20 0 |  |
|---------------------------|--------|-------------------|---------|--|
| PARAMETER                 | SYMBOL | RATINGS           | UNIT    |  |
| Repetitive Peak Voltage   | VRM    | 30                | V       |  |
| Reverse Voltage(DC)       | VR     | 30                | V       |  |
| Forward Current(Average)  | lF(AV) | 100               | mA      |  |
| Non Continuous            | IFSM   | 0.6               | Α       |  |
| Forward Surge Current*1   | IFSM   | 0.0               | A       |  |
| Junction Temperature      | Tj     | 125               | °C      |  |
| Storage Temperature Range | Tstg   | -55 <b>~</b> +150 | °C      |  |



<sup>\*1 :</sup> Non continuous high amplitude 60Hz half-sine wave.





SOD-723

### ■MARKING RULE



- ①: 0 (Product Number)
- 2: Assembly Lot Number

## **■**PRODUCT NAME

| PRODUCT NAME | DESCRIPTION                       |  |  |
|--------------|-----------------------------------|--|--|
| XBS013S16R   | SOD-723                           |  |  |
| XBS013S16R-G | SOD-723 (Halogen & Antimony free) |  |  |

<sup>\*</sup> The "-G" suffix indicates that the products are Halogen and Antimony free as well as being fully RoHS compliant.

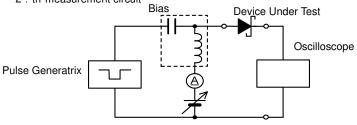
## **■**ELECTRICAL CHARACTERISTICS

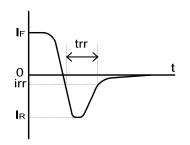
Ta=25°C

| PARAMETER SYMBOL        | CVMPOL   | TEST CONDITIONS                                | LIMITS |      |      | UNIT |
|-------------------------|----------|------------------------------------------------|--------|------|------|------|
|                         | STIVIBOL | TEST CONDITIONS                                | MIN.   | TYP. | MAX. | UNIT |
| Forward Voltage VF1 VF2 | VF1      | I <sub>F</sub> =1mA                            | -      | 0.31 | -    | V    |
|                         | VF2      | $I_F=100 \text{mA}$                            | -      | 0.71 | 1    | V    |
| Reverse Current         | lr       | V <sub>R</sub> =25V                            | -      | -    | 2    | μΑ   |
| Inter-Terminal Capacity | Ct       | $V_R=0V$ , $f=1MHz$                            | -      | 6    | -    | pF   |
| Reverse Recovery Time*2 | trr      | I <sub>F</sub> =I <sub>R</sub> =10mA , irr=1mA | -      | 2    | -    | ns   |

Ta=25°C

\*2 : trr measurement circuit



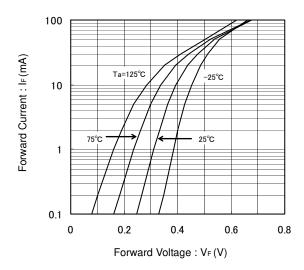


<sup>\*</sup> The device orientation is fixed in its embossed tape pocket.

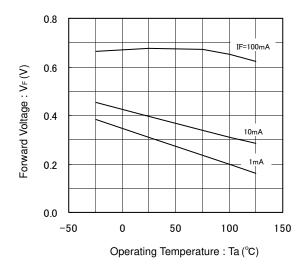
## XBS013S16R-G

## **■**TYPICAL PERFORMANCE CHARACTERISTICS

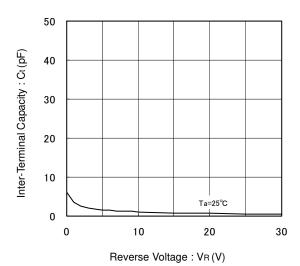
### (1) Forward Current vs. Forward Voltage



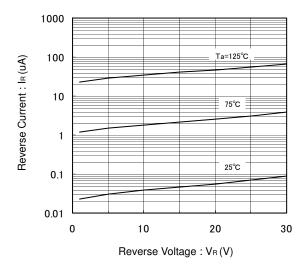
### (3) Forward Voltage vs. Operating Temperature



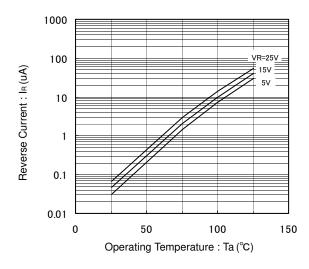
### (5) Inter-Terminal Capacity vs. Reverse Voltage



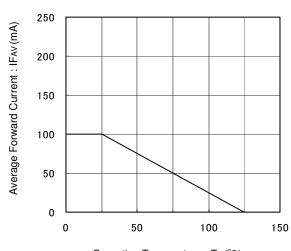
#### (2) Reverse Current vs. Reverse Voltage



### (4) Reverse Current vs. Operating Temperature



### (6) Average Forward Current vs. Operating Temperature



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